

9- and 11-Channel, Muxed Input LCD Reference Drivers

AD8509/AD8511

FEATURES

Single-Supply Operation: 3.3 V to 5 V

High Output Current: 300 mA Low Supply Current: 6 mA Stable with 1000 pF Loads Pin Compatible with LMC6009 Pin Compatible with CL-FP6131

APPLICATIONS LCD Driver

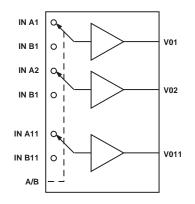
GENERAL DESCRIPTION

The AD8509 is a 9-channel (AD8511 an 11-channel) LCD reference driver designed to drive 64 gray scale column drivers. Each buffer has an A/B input used to select between two voltages for LCD displays. These buffers are used to drive the resistor ladders of LCD column drivers for gamma correction.

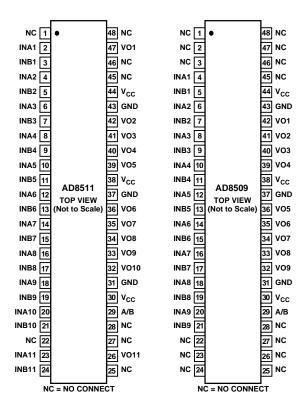
These LCD drivers have higher slew rates and output drive current than similar competitive parts. This increases the stability of the reference ladder, resulting in better gray scale and visual performance.

The AD8509 and AD8511 are specified over the -20° C to $+85^{\circ}$ C temperature range. They are available in 48-lead thin shrink small outline (TSSOP) surface mount packages in tape and reel.

FUNCTIONAL BLOCK DIAGRAM



PIN CONFIGURATIONS 48-Lead TSSOP (RU Suffix)



AD8509/AD8511-SPECIFICATIONS

ELECTRICAL CHARACTERISTICS ($V_s = +5 \text{ V}$, $T_A = +25 ^{\circ}\text{C}$, unless otherwise noted)

Parameter	Symbol	Conditions	Min	Тур	Max	Units
INPUT CHARACTERISTICS Offset Voltage Input Bias Current Voltage Gain	V _{OS} I _B A _{VO}		0.985		20 50	mV nA V/V
OUTPUT CHARACTERISTICS Output Voltage High Output Voltage Low Output Short Circuit Current	$V_{ m OH} \ V_{ m OL} \ I_{ m SC}$	$I_{LOAD} = +20 \text{ mA}$ $I_{LOAD} = -20 \text{ mA}$	4.8 120	350	200	V mV mA
POWER SUPPLY Load Regulation Load Regulation Supply Current Supply Current	LCD09 LCD11	$\begin{array}{c} V_{IN} = 0.5 \; V \; \text{-} \; 4.5 \; V \; , \; I_{SOURCE} = 20 \; mA \\ V_{IN} = 0.5 \; V \; \text{-} \; 4.5 \; V \; , \; I_{SINK} = 20 \; mA \\ I_{SY}, \; V_{IN} = 2.5 \; V \\ I_{SY}, \; V_{IN} = 2.5 \; V \end{array}$		7 7	8.5 10	mV mV mA mA
DYNAMIC PERFORMANCE Slew Rate Slew Rate Settling Time	t_{S}	$C_{\rm L}$ = 15 pF $R_{\rm L}$ = 250 Ω IDC = 13 mA (Sink/Source)		7 6.2 3	6	V/μs V/μs μs
LOGIC INPUT CHARACTERISTICS Input Current Low Input Current High Input Voltage Low Input Voltage High	I _{IL} I _{IH} V _{IL} V _{IH}		2.0		1.0 1.5 0.8	μΑ μΑ V V

Specifications subject to change without notice.

ABSOLUTE MAXIMUM RATINGS*

Supply Voltage +7 V
Input Voltage GND to V _S
Storage Temperature Range
RU Package
Operating Temperature Range
AD8509A/AD8511A20°C to +85°C
Junction Temperature Range
RU Package
Lead Temperature Range (Soldering, 60 sec) +300°C
*Stresses above those listed under Absolute Maximum Ratings may cause perma-
nent damage to the device. This is a stress rating only; the functional operation of
the device at these or any other conditions above those indicated in the operational
sections of this specification is not implied. Exposure to absolute maximum rating
conditions for extended periods may affect device reliability.

Package Type θ_{JA}^* θ_{JC} Units48-Lead TSSOP (RU)11542°C/W

NOTE

 $^*\theta_{JA}$ is specified for the worst case conditions, i.e., θ_{JA} specified for device soldered in circuit board for surface mount packages.

ORDERING GUIDE

Model Temperature		Package	Package	
Range		Description	Options	
AD8509ARU*	-20°C to +85°C	48-Lead TSSOP		
AD8511ARU*	-20°C to +85°C	48-Lead TSSOP		

 $^{^{\}ast}$ Available in 2,000 piece reels only.

Table I. MUX Function

A/B Select (Pin 29)	Input
Logic HI	INAx
Logic LOW	INBx

CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the AD8509/AD8511 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



-2- REV. 0

Typical Performance Characteristics—AD8509/AD8511

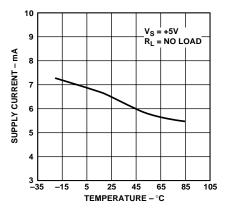


Figure 1. Supply Current vs. Temperature

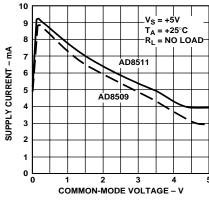


Figure 2. Supply Current vs. Common-Mode Voltage

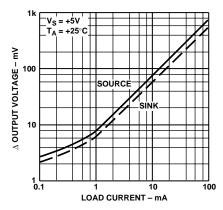


Figure 3. Output Voltage to Supply Rail vs. Load Current

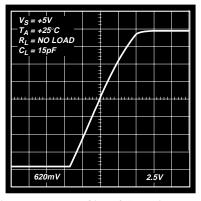


Figure 4. Large Signal Transient Response – Rising

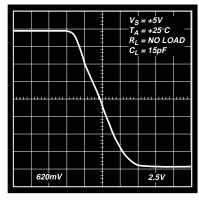


Figure 5. Large Signal Transient Response – Falling

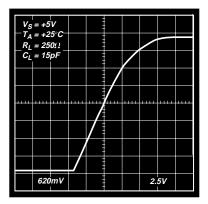


Figure 6. Large Signal Transient Response – Rising

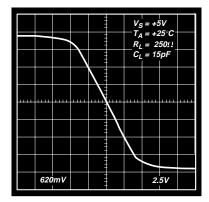


Figure 7. Large Signal Transient Response – Falling

REV. 0 -3-

AD8509/AD8511

APPLICATIONS

The AD8509 and AD8511 are CMOS buffers with A/B inputs, which are used to select between two different reference voltages set up by an external resistor ladder. Input bias currents are orders of magnitude less than competitive parts, allowing very large resistor ladders to be used to save supply current. A guaranteed value of 50 nA is much higher than actual values and is limited by leakage in the test system.

Buffer outputs are designed to drive resistive loads. They are also stable with capacitive loads, so no resistors should be used in series with these outputs to attain the best display performance. Outputs have high slew rates and 6 μ s settling times. Each output is capable of delivering a minimum of 120 mA, assuring fast response to varying loads.

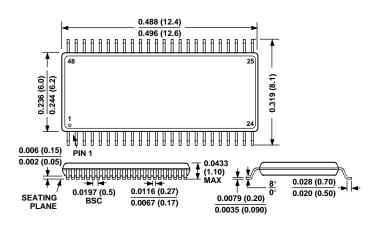
The AD8509 is a 9-channel buffer and is similar to the LMC6009 in functionality. The AD8511 is an 11-channel buffer similar to the CL-FP6131. However, the control to select either 9- or 11-channel operation, the EN_11 pin of the CL-FP6131, is not available on the AD8511. If 9-channel operation is desired, use the AD8509.

Power supply pins on the AD8509 and AD8511 have multiple ground and $V_{\rm CC}$ connections. Because of the high peak currents that these buffers can deliver, it is strongly recommended that all be connected, and that the $V_{\rm CC}$ pins be suitably bypassed.

OUTLINE DIMENSIONS

Dimensions shown in inches and (mm).

48-Lead TSSOP (RU Suffix)



-4- REV. 0